

Influence of reaction parameters on crystal phase growth and optical properties of ultrasonic assisted Hydro-and solvothermal synthesized sub-micrometer-sized CdS spheres

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Abstract

Sub-micrometer-sized CdS spheres were synthesized by hydrothermal and solvothermal reactions using $\text{Cd}(\text{NO}_3)_2 \cdot 4\text{H}_2\text{O}$ and $\text{CH}_4\text{N}_2\text{S}$ raw materials at a constant stoichiometric 1 : 2, Cd : S molar ratio. Various conditions such as solvent type (water and/or ethanol), reaction time and temperature were examined for the synthesis of the targets. The synthesized materials were characterized by powder X-ray diffraction (PXRD) technique and fourier-transform infrared (FTIR) spectroscopy. Crystal structure study was performed in a comparison mode to investigate the crystalline phase purity and growth of the obtained CdS materials when the reaction conditions were changed. The PXRD data indicated that the as-synthesized materials were crystallized well in a hexagonal crystal system with the space group $\text{P6}_3\text{mc}$. However, the crystal phase growth study showed that a cubic crystal system of CdS was obtained as a second crystal phase in the mixture. The morphologies of the synthesized materials were studied by field emission scanning electron microscopy (FESEM) technique. The data showed that the reaction solvent had a critical influence on the morphology of the obtained materials. Ultraviolet-visible spectra showed that the synthesized CdS materials had strong light absorption in the ultraviolet-visible light regions. The calculated direct optical band gap energies of the obtained materials were in the ranges of 1.90-2.30 eV.

Keywords: Cadmium Sulfide; Crystal Phase; Hydrothermal; Optical Property; Purity.

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INTRODUCTION

Among the II-VI semiconductors, cadmium sulphide (CdS) is one of the most important wide gap semiconductors with $E_g \approx 2.5$ eV for the bulk hexagonal wurtzite phase and $E_g \approx 3.53$ eV for the bulk cubic phase. In particular, many researchers have carried out studies on CdS because of its numerous applications as photocatalyst, solar cells and light-emitting diodes [1-4], piezoelectric [5], optoelectronic [6], etc. Different methods have been reported for the preparation of CdS materials, such as solid-state methods [7,8], solvothermal [9-11], precipitation [12-16], microwave-assisted solvothermal [17],

liquid-crystal templating [18], calcinations of Cd-thiolates [19], vapor-liquid-solid [20], template [21], aqueous-solution process [22], thermal evaporation [23], chemical vapor deposition [24], microwave irradiation [25], hydrothermal [26-33], electrochemical [34], Spray-Pyrolysis [35], direct vapor transport [36], electrodeposition [37], laser ablation [38], microemulsion [39], microwave [40], sonochemical [41], microwave assisted sol-gel [42] methods, etc. Among various techniques, hydrothermal reaction is a powerful method providing a material with high crystal phase purity, nano-sized particles and controlled stoichiometry of CdS powder [43, 44]. Hydrothermal name has

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Greek origin which is composed of two words 'hydros' meaning water and 'thermos' meaning heat and can be defined as any heterogeneous reaction in the presence of aqueous solvents or mineralizes under high pressure and temperature conditions to dissolve and recrystallize (recover) materials that are relatively insoluble under ordinary conditions. This method can be as an important tool for advanced materials processing and used in preparation of mono dispersed and highly homogeneous nanoparticles and nano-hybrid and nanocomposite materials. The mentioned method has potential advantages of relatively low cost, high purity, energy saving, nucleation control, avoidance of pollution, high dispersion, high rate of reaction, shape control, and low temperature operations in the presence of the solvent [43].

In the present study, ultrasonic assisted hydrothermal and solvothermal routs are applied for the synthesis of sub-micron structured CdS powders using $\text{Cd}(\text{NO}_3)_2 \cdot 4\text{H}_2\text{O}$ and $\text{CH}_4\text{N}_2\text{S}$ raw materials. Different reaction conditions such solvent type, time and temperature are studied for their influence on the purity, crystal phase type and growth of the synthesized materials. The crystallographic data are extracted and compared to study the crystallite size, crystal phase purity and growth. The optical properties of the obtained materials are also investigated by UV-Vis and FTIR spectroscopies.

EXPERIMENTAL

Materials and instruments

All chemicals including $\text{Cd}(\text{NO}_3)_2 \cdot 4\text{H}_2\text{O}$, $\text{CH}_4\text{N}_2\text{S}$, NH_4OH , deionized distilled water and ethanol were of analytical grade, obtained from commercial sources (Merck Company) and used without further purifications. Phase identifications were performed on a powder X-ray diffractometer D5000 (Siemens AG, Munich, Germany) using CuK_α radiation. The morphology of the obtained materials was examined with a field emission scanning electron microscope (Hitachi FE-SEM model S-4160). FTIR spectra were recorded on a Tensor 27 spectrometer (Bruker Corporation, Germany). Absorption spectra were recorded on a UV-visible spectrophotometer model-UV-1650 PC (Shimadzu, Japan). Cell parameter refinement was reported by celref software version 3 (Laboratoire des Matériaux et du Génie Physique de l'École Supérieure de Physique de Grenoble). Ultrasonic

device (SOLTEC, Italy) with the power of 305 W was used.

Synthesis of CdS samples

In a typical experiment, 3.084 g (10.0 mmol) of $\text{Cd}(\text{NO}_3)_2 \cdot 4\text{H}_2\text{O}$ ($M_w = 308.4 \text{ g mol}^{-1}$) was dissolved in a 15 mL of solvent (deionized distilled water) (solution 1). In another beaker, 1.522 g (20 mmol) of $\text{CH}_4\text{N}_2\text{S}$ ($M_w = 76.0 \text{ g mol}^{-1}$) was dissolved in a 15 mL of the mentioned solvent (solution 2). Afterwards, the solution 2 was added to the solution 1 drop wise while stirring. The pH value of the final solution was adjusted in the range of 9-10 using NH_4OH solution. The obtained solution was agitated further for 1 h and then ultrasonicated for 1 h. The resultant solution was transferred into a 100-mL Teflon lined stainless steel autoclave. The autoclave was sealed and treated thermally at 120°C for 48 h (S_1), 150°C for 48 h (S_2), 150°C for 72 h (S_3), 150°C for 96 h (S_4), and 180°C for 48 h (S_5). When the reaction was completed, the autoclave was cooled to room temperature by quenching with water immediately. The prepared powder was washed with distilled water and dried at 80°C for 3 h under normal atmospheric condition. An orange color powder was collected.

For the synthesis of S_6 and S_7 , the synthesis procedure explained for S_1 was followed. However, in this case, the solvent type is ethanol and the reaction temperature is 180°C for 48 h (S_6) and 72 h (S_7).

For the synthesis of S_8 , S_9 and S_{10} , the synthesis procedure explained for S_1 was used. In this case, the solvent type is a 1 : 1 volumetric mixture of water and ethanol. The reaction temperature is 180°C for 48 h (S_8), 72 h (S_9) and 96 h (S_{10}).

RESULTS AND DISCUSSIONS

Characterization

The PXRD patterns of the obtained materials are classified and shown in Figs. 1-4. The data show that all the diffraction patterns match exactly to the hexagonal wurtzite-structure with the space group $P6_3mc$ (JCPDS Card No. 41-1049). The diffraction peaks are indexed to (1 0 0), (0 0 2), (1 0 1), (1 0 2), (1 1 0), (1 0 3), (1 1 2), (2 0 3) and (2 1 1) diffraction planes of the wurtzite CdS crystalline phase, respectively. The data show that the peaks at (111) (broad and overlapped peak with the (0 0 2) peak in the hexagonal crystal system), (2 0 0), (4 0 0) and (3 3 1) diffraction planes are corresponded to the cubic CdS crystal

system (space group: F-43m, JCPDS Cards, No. 10-0454). To make a useful and comprehensive comparison study, the PXRD patterns are classified based on reaction time, temperature and solvent type. Fig. 1 a-c shows the PXRD patterns of the obtained samples when the solvent type is water and the reaction time is 48 h. The figure shows that when the reaction temperature is 120 °C, there is an obvious impurity cubic CdS peak position at $2\theta=31^\circ$ in the mixture. The peaks with the h k l values of 200, 112 and 201 at about 50 to 55° are combined and become a single peak that is attributed to the cubic CdS crystal phase. However, with increase the reaction time to 150 and then 180 °C, the impurity peak is disappeared and the peak corresponded to the wurtzite crystal

system (1 0 1) is grown considerably. In this case, the mentioned three peaks are appeared as three separated peaks showing the good crystallinity of hexagonal crystal system.

Fig. 2 a-c shows the PXRD patterns of the obtained materials when the reaction solvent is H₂O, reaction temperature is 150°C and reaction times change from 48 h to 96 h. The data show that there is no considerable change in the crystal phase purity when the reaction time increased. However, the counts values show that when the reaction time is 72 h, the crystal phase growth is retrograded. The phenomenon is maybe because of changing the cubic crystal phase to the hexagonal crystal system when the reaction time is 72 h. This can be seen from increasing the growth

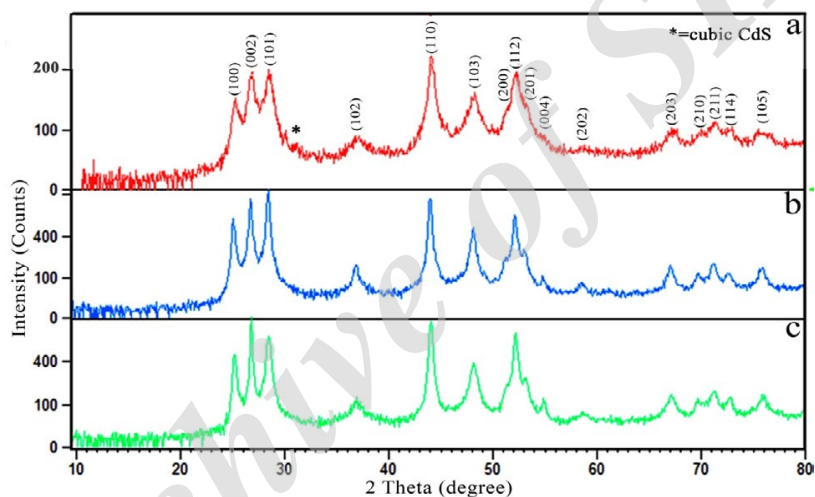


Fig. 1. PXRD patterns of a) S₁, b) S₂ and c) S₃.

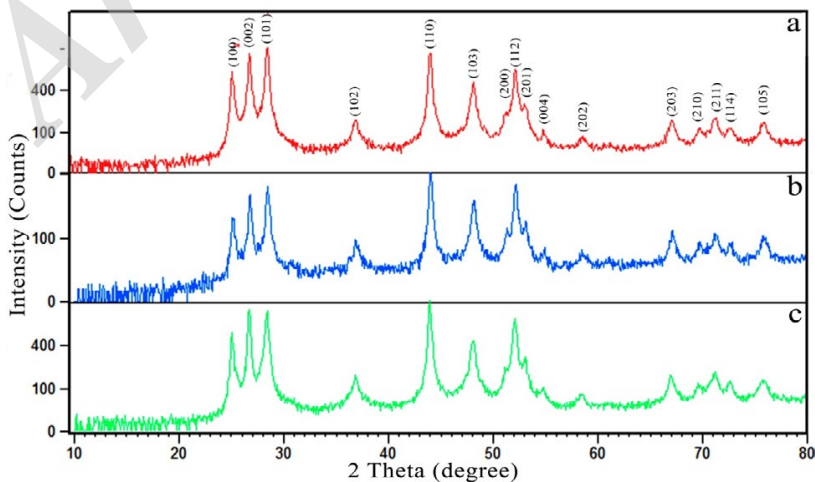


Fig. 2. PXRD patterns of a) S₂, b) S₃ and c) S₄.

of the peak at (1 0 1) compared to the overlapped peak (0 0 2). However, the crystal phase growth is improved again when the reaction time was increased to 96 h. In other words, when the crystal phase change is completed, the hexagonal crystal phase is grown again with increase the reaction time to 96 h.

Fig. 3 a-c shows the PXRD data of the obtained materials at 180°C for 48, 72 and 96 h. The solvent is a mixture of 1 : 1, H₂O : Ethanol. The PXRD data show that the materials have a high crystalline hexagonal CdS phase. As it can be seen from the data, the mixture of H₂O and ethanol as the reaction solvent has a considerable influence on the crystal phase growth of the target. However, it is clear that when the reaction time is 48 h, there

is an impurity peak corresponded to the cubic CdS crystal system. When the reaction time is increased to 96 h, the cubic impurity, marked with *, is disappeared. But the peak intensity at (0 0 2) is increases compared to the peak at (1 0 1). This indicates that increasing the reaction time to 96 h changes the crystal phase stability from hexagonal to cubic crystal system.

Fig. 4 a-d shows the PXRD patterns of obtained materials when the solvents are H₂O and a 1 : 1 mixture of H₂O : Ethanol, at 180°C for 48 h; and ethanol, at 180°C for 48 and 72 h. The data show that when the solvent is ethanol and the mixture of H₂O and ethanol, the material is composed of the mixtures of hexagonal [7-10] and cubic [46-48] CdS crystal phases. But, H₂O can advance the

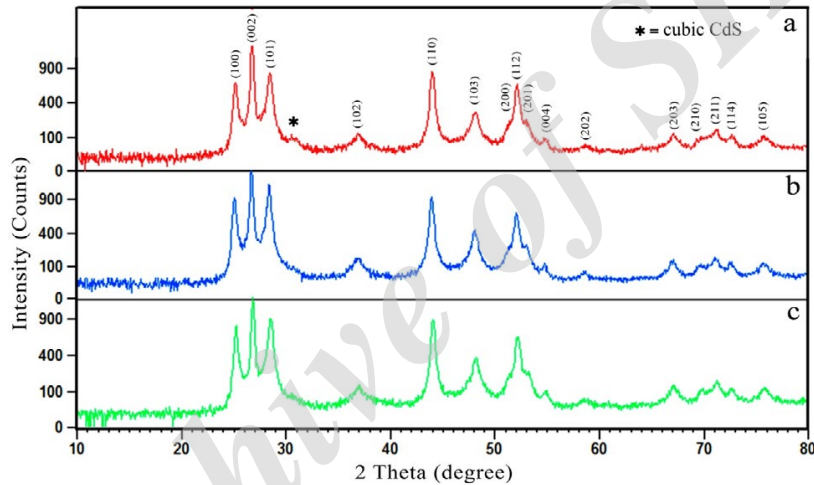


Fig. 3. PXRD patterns of a) S₈, b) S₉ and c) S₁₀.

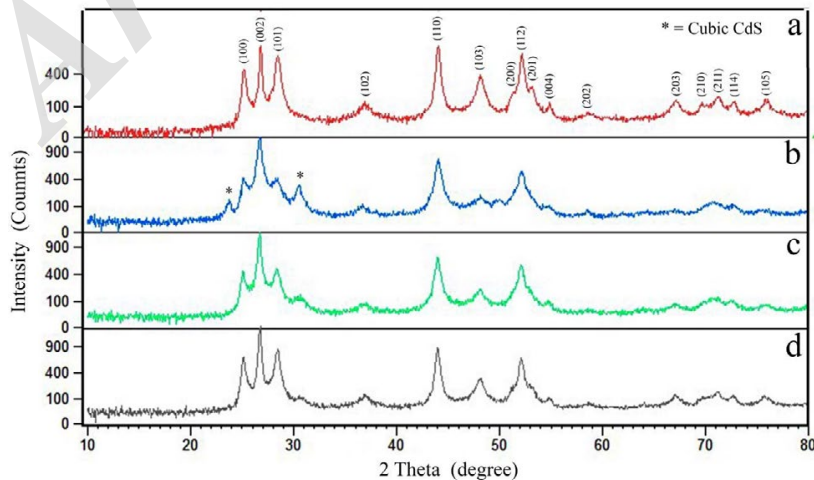


Fig. 4. PXRD patterns of a) S₅, b) S₆, c) S₇ and d) S₈.

process in a way that no obvious impurity phase is present in the PXRD pattern.

To study the solvent type, reaction time and temperature influences on the crystal phase purity and growth, the phase composition was calculated from the integrated intensities of the wurtzite (1 0 0) peak ($2\theta \approx 25.2^\circ$) and the overlapping sphalerite (1 1 1) and wurtzite (0 0 2) peaks ($2\theta \approx 26.8^\circ$). In the mixed phase products, the weight fraction of wurtzite (F_w) can be estimated as below:

$$F_w = \frac{R}{K} - (kk' - 1)R$$

Where R represents the intensity ratio of wurtzite peak (1 0 0) to the overlapping peak (measured), $k' = 0.825$ is the intensity ratio of the wurtzite peak (0 0 2) to peak (1 0 0) (standard pattern), and $k = 0.341$ is the intensity ratio of the wurtzite peak (1 0 0) to the sphalerite peak (1 1 1) (standard pattern) [44].

According to the data, F_w value for S_3 , S_6 , S_9 and S_{10} is below 2. The observation indicates that reaction time is a main factor on the wurtzite crystal phase purity. The lowest amounts are for S_9 and S_{10} . This shows that ethanol as a reaction solvent cannot force the reaction in an effective way to produce a purer wurtzite crystal phase. However, when the solvent is H_2O and the reaction temperature is $150^\circ C$ for S_2 and S_5 , F_w value is maximized.

Table 2 shows the crystallite size data of the obtained materials calculated by Scherrer equation:

$$D = \frac{K\lambda}{B_{1/2} \cos\theta}$$

In this equation, D is the entire thickness of the crystalline sample, λ is the X-ray diffraction wavelength (0.154 nm), K is Scherrer constant (0.9), $B_{1/2}$ (rad) of FWHM is the full width at half its maximum intensity and θ is the half diffraction angle at which the peak is located. The data reveal that when the reaction time and temperature are 48 h and $120^\circ C$, respectively, and the solvent type is H_2O (S_1), the crystallite size is largest compared to the other synthesized samples. Surprisingly, the table shows that the crystallite size is decreased when the reaction time and temperature are increased to 96 h and $180^\circ C$, respectively. Besides, the data indicate that the crystallite sizes of S_1 - S_5 , when the solvent is H_2O , are larger than those of the other types of the solvents.

The value of the dislocation density (δ (lines/ m^2) $\times 10^{14}$) which is related to the number of defects in the crystal was calculated from the average values of the crystallite size (D (nm)) by the relationship (3.3) given below:

$$\delta = \frac{1}{D^2}$$

Table 2. Crystallite size data of the as-synthesized materials.

Sample	$I_{(100)}$	$I_{(002)}$	$I_{(101)}$	$I_{(100)}/I_{(002)}$	$I_{(101)}/I_{(002)}$	Fw
S_1	220	371	378	0.592992	1.018868	2.164421
S_2	567	805	940	0.704348	1.167702	2.570870
S_3	438	867	637	0.505190	0.734717	1.843944
S_4	167	271	314	0.616236	1.158672	2.249261
S_5	485	750	745	0.646667	0.993333	2.360335
S_6	640	1327	786	0.482291	0.592313	1.760362
S_7	893	1447	1182	0.617139	0.816862	2.252557
S_8	740	1208	856	0.612583	0.708609	2.235928
S_9	401	1215	397	0.330041	0.326749	1.204650
S_{10}	429	1199	456	0.357798	0.380317	1.305963

Table 1. Phase composition properties of the obtained samples.

Sample	2θ	$\cos(\theta)$	$B_{1/2}$	D	δ	ε
S_1	43.98	0.9272	0.004120	36	7.716049	0.955016
S_2	43.9091	0.9275	0.005150	29	11.89061	1.194156
S_3	43.8749	0.9276	0.006179	24	17.36111	1.432910
S_4	43.9303	0.9274	0.005373	28	12.75510	1.245730
S_5	43.9801	0.9272	0.005150	29	11.89061	1.193770
S_6	43.9622	0.9273	0.006866	22	20.66116	1.591710
S_7	43.8864	0.9276	0.006866	22	20.66116	1.592225
S_8	44.008	0.9272	0.006866	22	20.66116	1.591539
S_9	44.0189	0.9272	0.006866	22	20.66116	1.591539
S_{10}	44.0132	0.9272	0.006866	22	20.66116	1.591539

The strain ($\varepsilon \times 10^{-3}$) values were determined with the use of the following formula:

$$\varepsilon = \frac{\beta_{hkl} \cos\theta}{4}$$

The data show that the dislocation density and strain values are depend on the crystallite size and FWHM values. The data show that the values were increased when the crystal sizes were decreased.

The crystallographic data of the obtained samples were calculated and compared using the peak with the miller indices 110 corresponded to the hexagonal CdS crystal system. The data are summarized in Table 3.

The below equations are used to calculate the d values:

$$n\lambda = 2d \sin\theta$$

And

$$\frac{1}{d^2} = \frac{4(h^2 + hk + k^2)}{3a^2} + \frac{l^2}{c^2}$$

Using the peak with the (h k l) value of (1 1 0), the relation is as below:

$$\frac{1}{d^2} = \frac{8}{3a^2}$$

With simplifying the above equation, we obtain:

$$d = \sqrt{\frac{3}{8}} a$$

Besides, the unit cell volume can be obtained from the bellow formula:

$$V = \frac{\sqrt{3}}{2} c^2 a$$

Where a and c are the lattice parameters calculated by celref software and V is the cell volume.

The obtained data show that the calculated d values by Bragg equation (2) and (3) are not so in accordance with each other's. The difference is 0.46 Å. The difference is maybe due to uncertainty of the used cell parameter in eq.3 and the 2θ value used in eq.2. The uncertainty is obvious from the high dislocation density and strain values.

Morphology analysis

Fig. 5 shows the FESEM images of S_1 - S_5 . The images of S_1 , S_2 and S_5 show that when the reaction time is 48 h, increasing the reaction temperature has no significant effect on the morphology of the targets. The data show that the material is composed of particle and also sphere structures. It is obvious from the images that when the reaction temperature is 150 °C, indicated with a, b and c, produces the material with almost particle morphology. However, when the reaction temperature is 120 and 180°C, the morphology of the targets is large size sphere.

Fig. 6 shows the FESEM images of S_6 and S_7 . The images show that ethanol as the reaction solvent has an effect on the homogeneity of the obtained target. It is clear that the morphology homogeneity is better compared to S_1 - S_4 .

Fig. 7 shows the FESEM images of S_8 to S_{10} . The images show that when the reaction time is 48 h, the morphology is almost particle. However, the morphology becomes a mixture of particle and micro sphere when the reaction time is increased to 96 h.

All the FESEM images reveal that morphology of the targets depends on the solvent type and reaction time, considerably. If the morphology of highly homogeneous particle is desired, so the reaction procedure for the synthesis of S_2 and S_8 is applicable. However, when the material with sphere morphology is needed, the process for the synthesis of S_1 , S_5 , S_9 and S_{10} can be used.

Table 3. Lattice parameters and inter planar spacing data of the obtained materials.

Sample	a (Å)	c (Å)	d_{Bragg} (Å)	d_{cal} (Å)	V_{cal} (Å ³)
S_1	4.1154	6.6456	2.05860	2.520271	157.3977
S_2	4.1211	6.6795	2.06206	2.523762	159.2278
S_3	4.1262	6.6820	2.06357	2.526885	159.5442
S_4	4.1137	6.6912	2.05939	2.519230	159.4992
S_5	4.1119	6.6810	2.05887	2.518128	158.9437
S_6	4.1144	6.6863	2.05967	2.519659	159.2928
S_7	4.1213	6.6925	2.06305	2.523884	159.8560
S_8	4.1106	6.6811	2.05796	2.517331	158.8982
S_9	4.1073	6.7103	2.05715	2.515311	160.1615
S_{10}	4.1114	6.7022	2.05741	2.517821	159.9346

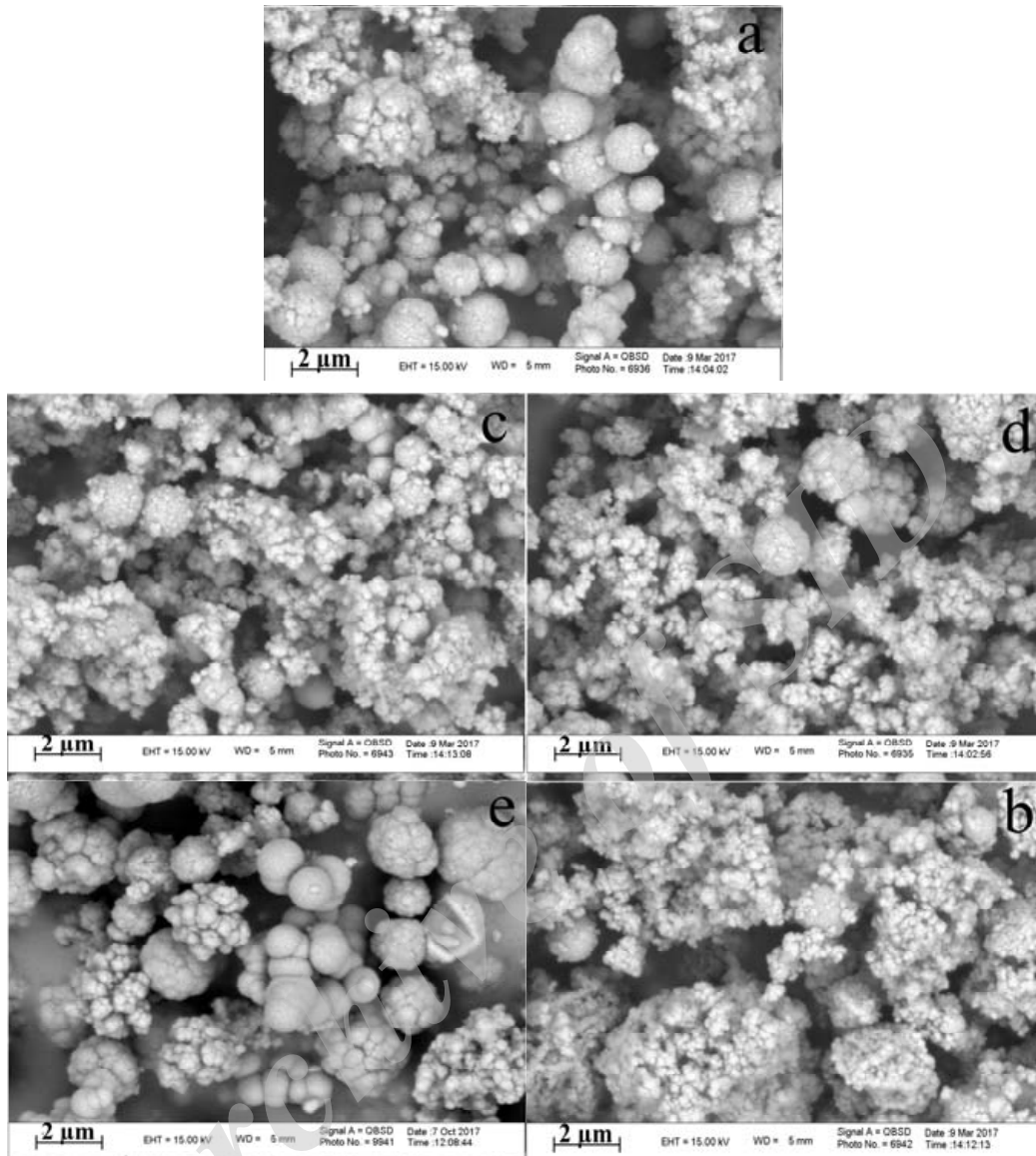


Fig. 5. FESEM images of a) S_1 , b) S_2 , c) S_3 , d) S_4 and e) S_5 .

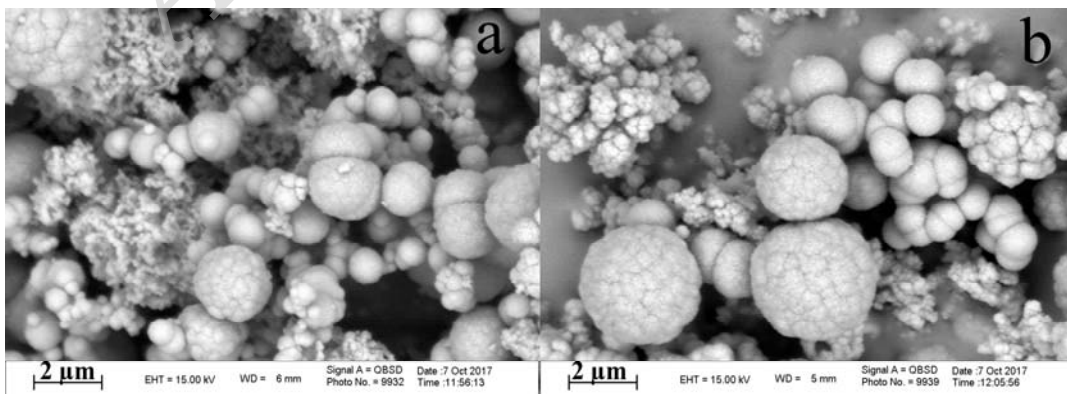


Fig. 6. FESEM images of a) S_6 and b) S_7 .

Optical properties

UV-Vis spectra and the calculated direct optical band gap energies of the CdS materials obtained from the absorption spectra are shown in Figs. 8 a-c and 9 a-c, respectively. According to the results of Pascual *et al.* [49], the relation between the absorption coefficient and incident photon energy can be written as $(\alpha h\nu)^2 = A(h\nu - E_g)$, where A and E_g are a constant and the direct band gap energy, respectively. Direct band gap energies were evaluated from extrapolating the linear part of the curve to the energy axis.

Fig. 9 a-c shows that the direct optical band gaps are 2.15, 1.98, 2.23, 2.13 and 1.95 eV for S_1 , S_2 , S_3 , S_4 and S_5 , respectively.

The calculated band gap energies for S_1 , S_2 and S_5 in Fig. 9 a show that increasing the reaction temperature at a constant reaction time decreases the band gap energy values. The data show that when the reaction time and temperature are 48 h and 180°C, the smallest band gap value is achieved. Fig. 9 b shows that the direct optical band gap energies are 2.23 and 2.17 eV for S_6 and S_7 , respectively. The data show that increasing the

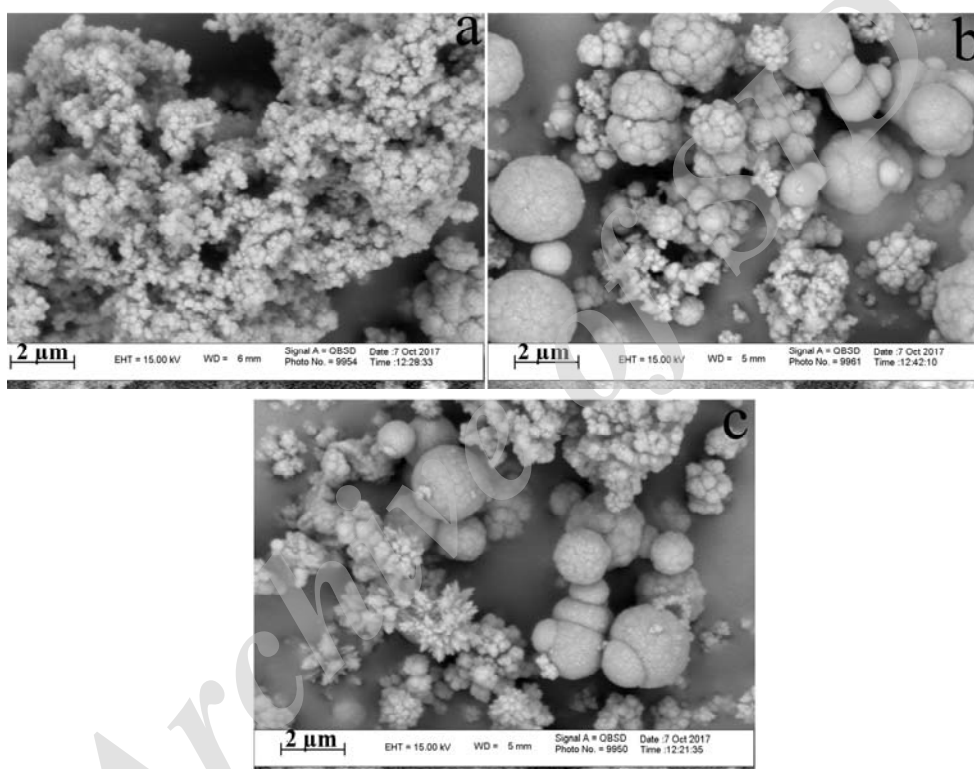


Fig. 7. FESEM images of a) S_8 , b) S_9 and c) S_{10} .

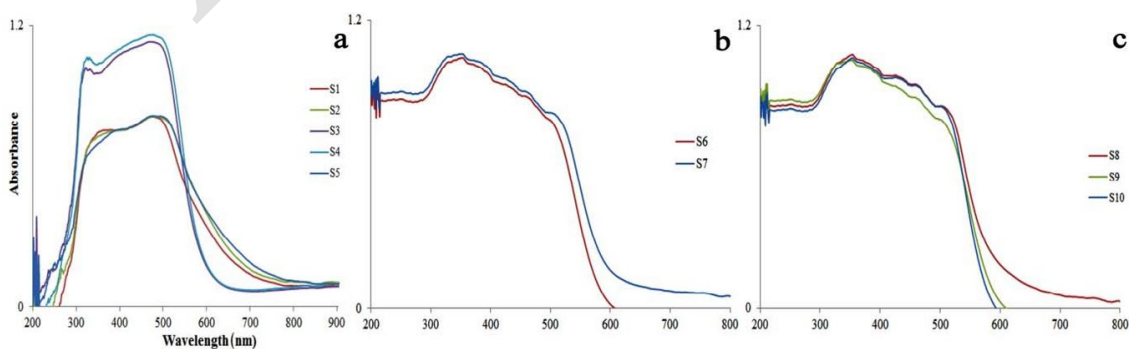


Fig. 8. UV-Vis absorption spectra of the obtained samples where a) S_1 - S_5 , b) S_6 - S_7 and c) S_8 - S_{10} .

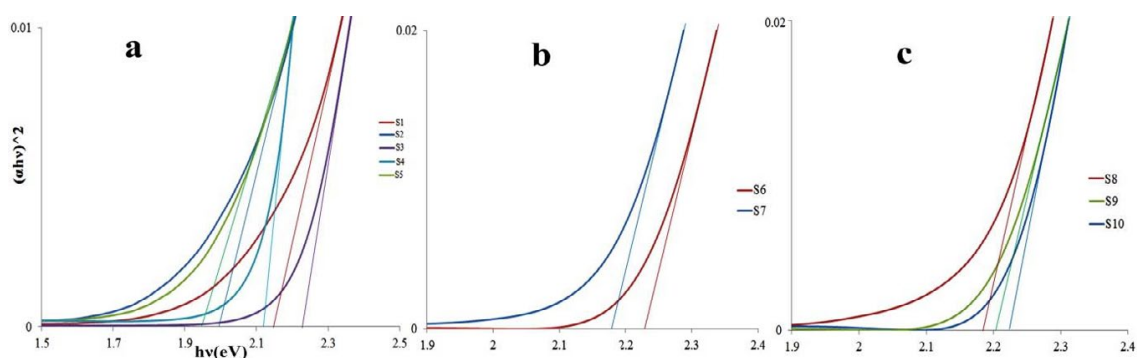


Fig. 9. Direct optical band gap energies of the obtained samples where a) S_1 - S_5 , b) S_6 - S_7 , and c) S_8 - S_{10} .

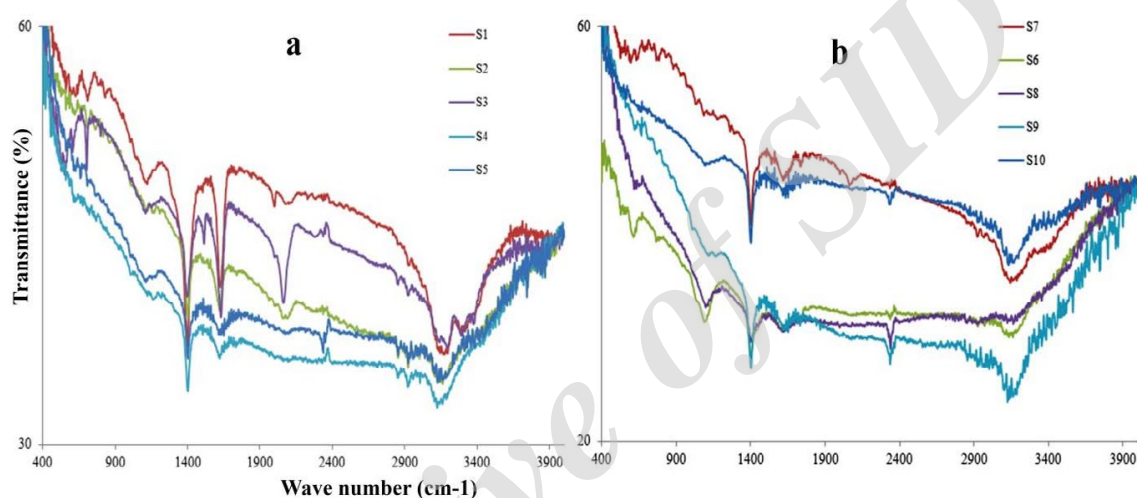


Fig. 10. FTIR spectra of the obtained materials where a) S_1 - S_5 and b) S_6 - S_{10} .

reaction time at a constant reaction temperature, 180 °C, with ethanol as the solvent, decreases the band gap energy. This trend is in agreement with that for S_1 - S_5 .

Fig. 9 c shows that the direct optical band gap energies are 2.18, 2.20 and 2.22 eV for S_8 , S_9 and S_{10} , respectively. It is obvious that increasing the reaction time at 180°C increases the band gap energy.

The band gap energy change behaviors indicate that reaction solvent has a critical influence on the optical band gap of the obtained materials. So, because lower optical band gap energy is favored for the catalytic applications, it is a useful guide for the synthesis of the desired CdS material. In the case, H_2O as the reaction solvent is a good medium for the synthesis of the obtained target.

Fig. 10 a and b shows the FTIR spectra of the obtained samples. There are some peaks at around 670, 705, 1074, 1394, 1510, 1577, 2050,

2327, 2906, 3103 and 3294 cm^{-1} . The peaks at 670 and 705 cm^{-1} , are assigned to Cd-S stretching vibrations [16]; the absorption peak at 1394 cm^{-1} is corresponded to S-C stretching vibration; the peaks at 1510 and 1577 cm^{-1} are assigned to stretching vibration of N-H in thiourea compound [16]; the very weak peak at 2906 cm^{-1} is attributed to Cd-O stretching vibration [50]; the peak at 3103 and 3294 are assigned to N-H stretching vibrations [27, 47, 51].

CONCLUSION

Ultrasonic assisted hydrothermal and solvothermal syntheses of CdS micro spheres were explored. Various conditions such as solvent type, reaction time and temperature were investigated using PXRD data for their influences on the crystal phase growth, purity and type of the as-synthesized materials. The phase composition data showed that when the reaction solvent was

H₂O, there was a surprisingly tendency to the hexagonal CdS crystal phase. The data showed that when the solvent was a mixture of H₂O and ethanol (S₈-S₁₀), the reaction was proceeded in a way that the solvent acted in a reverse order compared to H₂O reaction solvent (S₁-S₅) and the main crystal phase stability, hexagonal crystal structure, was decreased when the reaction time was increased. Besides, the crystallite size data showed that the sizes of the targets were smallest when the mixture of H₂O and ethanol was used as the reaction solvent. FESEM images data revealed that the morphology of the targets depended on the solvent type and reaction time, considerably. If highly homogeneous particle morphology was desired, the reaction procedure for the synthesis of S₂ and S₈ was applicable. However, when the material with sphere morphology was needed, the process for the synthesis of S₁, S₅, S₉ and S₁₀ could be used. The direct optical band gap energy changes were studied and related to the reaction parameters. The data showed that the smallest band gap energy was achieved when the reaction solvent was H₂O and the reaction time and temperature were 48 h and 180°C. At the end, the data showed that the reaction condition for the synthesis of S₅ was better than the others when purer crystal phase and low optical band gap energy was desired. However, when smaller crystallite size and high crystal growth were needed, the reaction conditions for the synthesis of S₁₀ were useful.

CONFLICT OF INTEREST

The authors declare that there are no conflicts of interest regarding the publication of this manuscript.

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